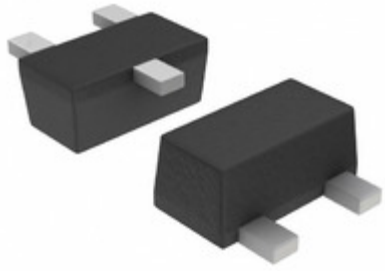

	<h2 style="color: #E67E22;">SI1013CX-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI1013CX-T1-GE3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET P-CH 20V 0.45A SC89-3
	Datenblätter:  SI1013CX-T1-GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 35716 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI1013CX-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 20V 0.45A SC89-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	35716 pcs Stock
detaillierte Beschreibung	P-Channel 20V 450mA (Ta) 190mW (Ta) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-89, SOT-490
Verlustleistung (max)	190mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	450mA (Ta)
Rds On (Max) @ Id, Vgs	760 mOhm @ 400mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	2.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	45pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V
Vgs (Max)	±8V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1013CX-T1-GE3DKR











































SI1013CX-T1-GE3 ist neu im Original, Suche SI1013CX-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1013CX-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1013CX-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1013R-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 350MA SC-75A</p>	 <p>SI1013R TI SI1013R TI</p>	 <p>SI1013-C-GM2 Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-VFLGA</p>	 <p>SI1013C-T1 VISHAY VISHAY SOT-323</p>
 <p>SI1013R-T1 VISHAY SI1013R-T1 VISHAY</p>	 <p>SI1013-A-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-WFQFN</p>	 <p>SI1013-C-GM2R Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 42-VFLGA</p>	 <p>SI1013R-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 350MA SC-75A</p>

heiße Teile

Mehr

 SI1000-C-GM	 SI1002-C-GMR	 SI1003-C-GM	 SI1011X-T1-GE3	 SI1011X-T1-GE3
 SI1012CR-T1-GE3	 SI1012CR-T1-GE3	 SI1012R-T1	 SI1012R-T1-E3	 SI1012R-T1-E3
 SI1012R-T1-GE3	 SI1012R-T1-GE3	 SI1012X-T1	 SI1012X-T1-E3	 SI1012X-T1-E3
 SI1012X-T1-GE3	 SI1012X-T1-GE3	 SI1013CX-T1-GE3	 SI1013R-T1	 SI1013R-T1-E3
 SI1013R-T1-E3	 SI1013R-T1-GE3	 SI1013R-T1-GE3	 SI1013X-T1	 SI1013X-T1-E3
 SI1013X-T1-E3	 SI1013X-T1-GE3	 SI1013X-T1-GE3	 SI1016CX-T1-GE3	 SI1016CX-T1-GE3
 SI1016X-T1-E3	 SI1016X-T1-E3	 SI1016X-T1-GE3	 SI1016X-T1-GE3	 SI1016X2-T1-GE3
 SI1021R-T1	 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1	 SI1022R-T1-E3
 SI1022R-T1-E3	 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-TI-E3	 SI1023CX-T1-GE3
 SI1023CX-T1-GE3	 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3	 SI1023X-T1-GE3

Contact us:Info@Y-IC.com

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